

MBRT40045

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MBRT40045 Information

	Part Number	MBRT40045	
800	Manufacturer	GeneSiC Semiconductor	
WWW House Cours	Category	Discrete Semiconductor Products Diodes - Rectifiers - Arrays	
	Description	DIODE MODULE 45V 400A 3TOWER	
	Package	Three Tower	
		For the pricing/inventory/lead time, please contact	
		us	
For Reference Only		Website: https://www.heisener.com	
- Omy		E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MBRT40045 Specifications

Manufacturer Part NumberMBRT40045ManufacturerGeneSiC SemiconductorCategoryDiscrete Semiconductor ProductsCategoryDiodes - Rectifiers - ArraysPackageThree TowerSeries-Diode Configuration1 Pair Common CathodeDiode TypeSchottkyVoltage - DC Reverse (Vr) (Max) @ H45VCurrent - Average Rectified (Io) (per Diode)400A (DC)Voltage - Forward (Vf) (Max) @ H750mV @ 200ASpeedFast Recovery Time (trr)Reverse Recovery Time (trr)-Current - Reverse Leakage @ VrInnA @ 20VOperating Temperature - Junction-55°C ~ 150°CMounting TypeChasis MountPackage / CaseThree Tower		
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	e - Junction	°C ~ 150°C
Package / Case Three Tower		assis Mount
		ree Tower
Supplier Device Package Three Tower	ige ,	ree Tower
Re		Report errors?

MBRT40045 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

MBRT40045 Payment Methods



If you have any question about MBRT40045, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com